



General Microtechnology & Photonics
Systems for Industry, Research, Telecom & Medicine

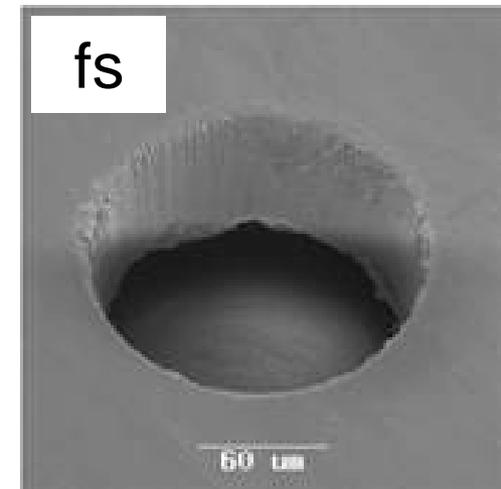
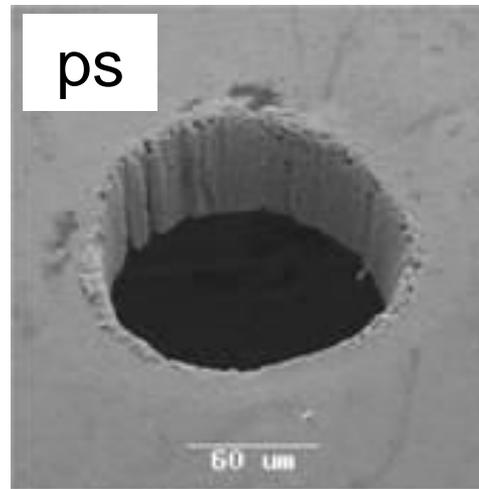
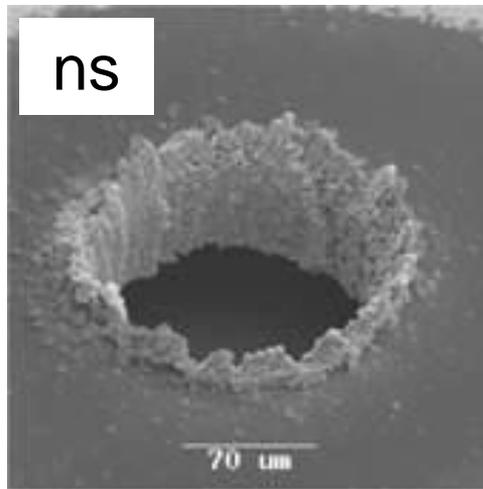
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Solution économique pour usinage laser picoseconde

Marcel Dubey

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marcel.dubey@gmp.ch

Usinage laser ultrarapide



- Durée d'impulsion
- Taux de répétition
- Profile du faisceau

Problèmes

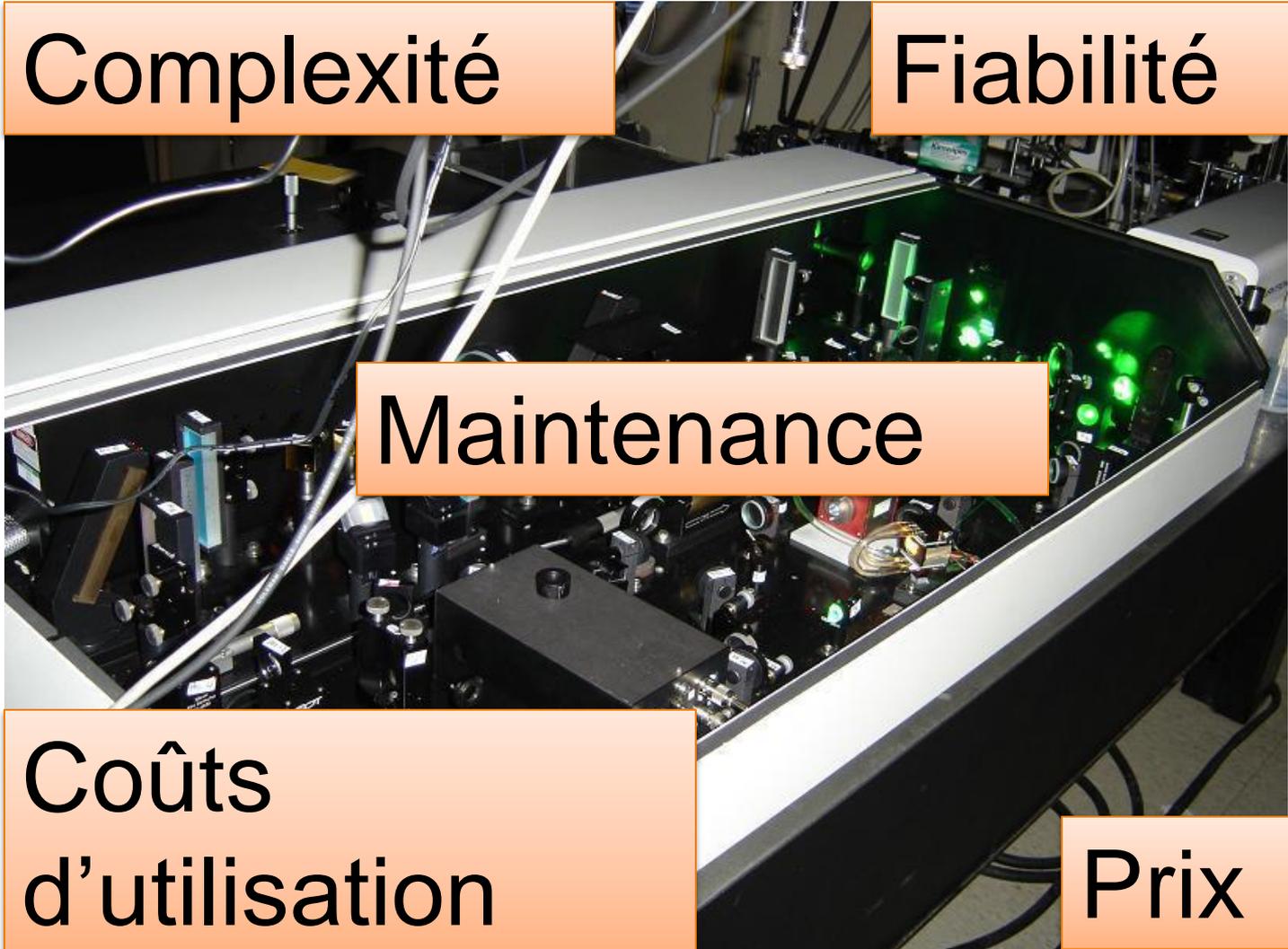
Complexité

Fiabilité

Maintenance

Coûts
d'utilisation

Prix

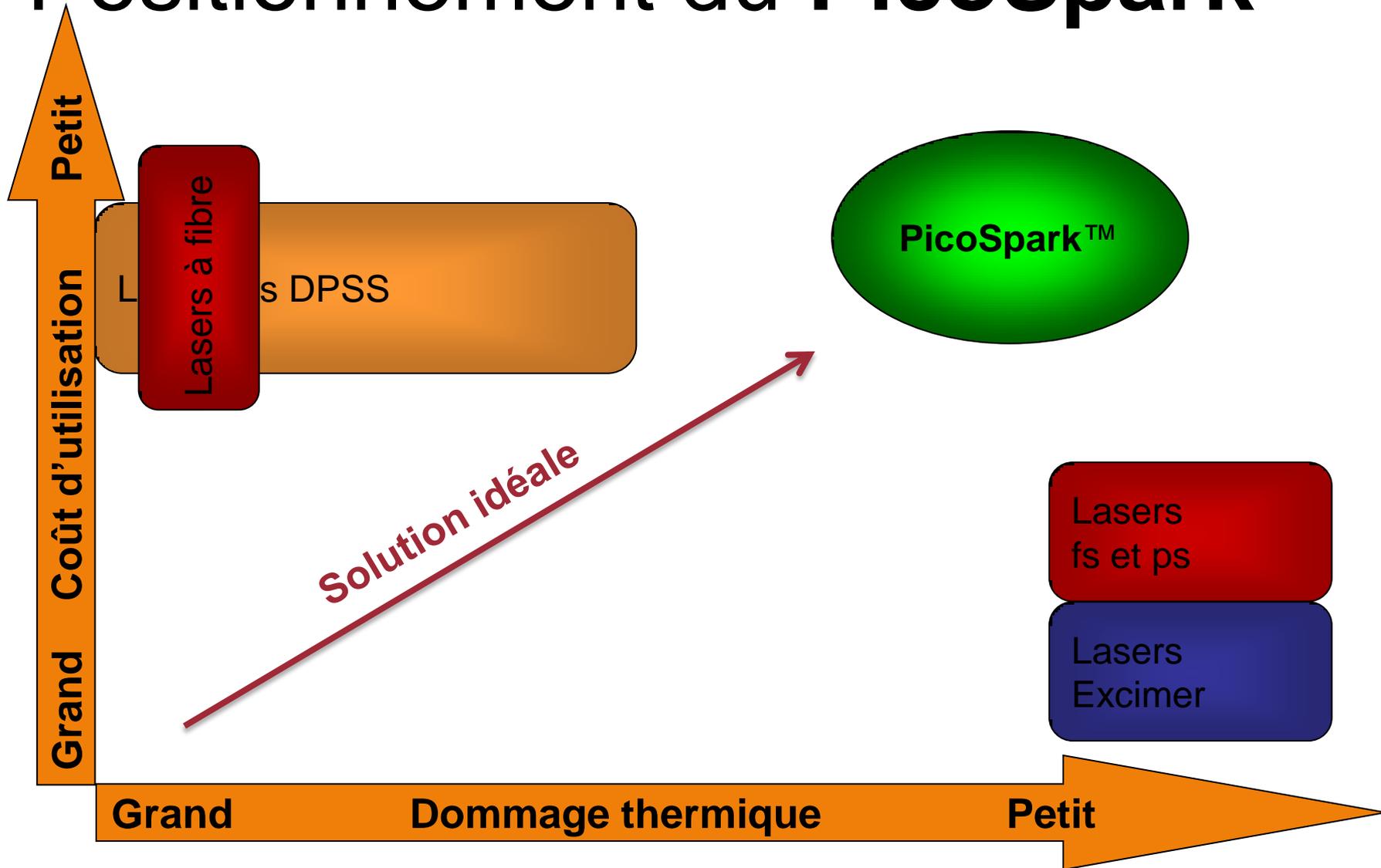


Solution : PicoSpark

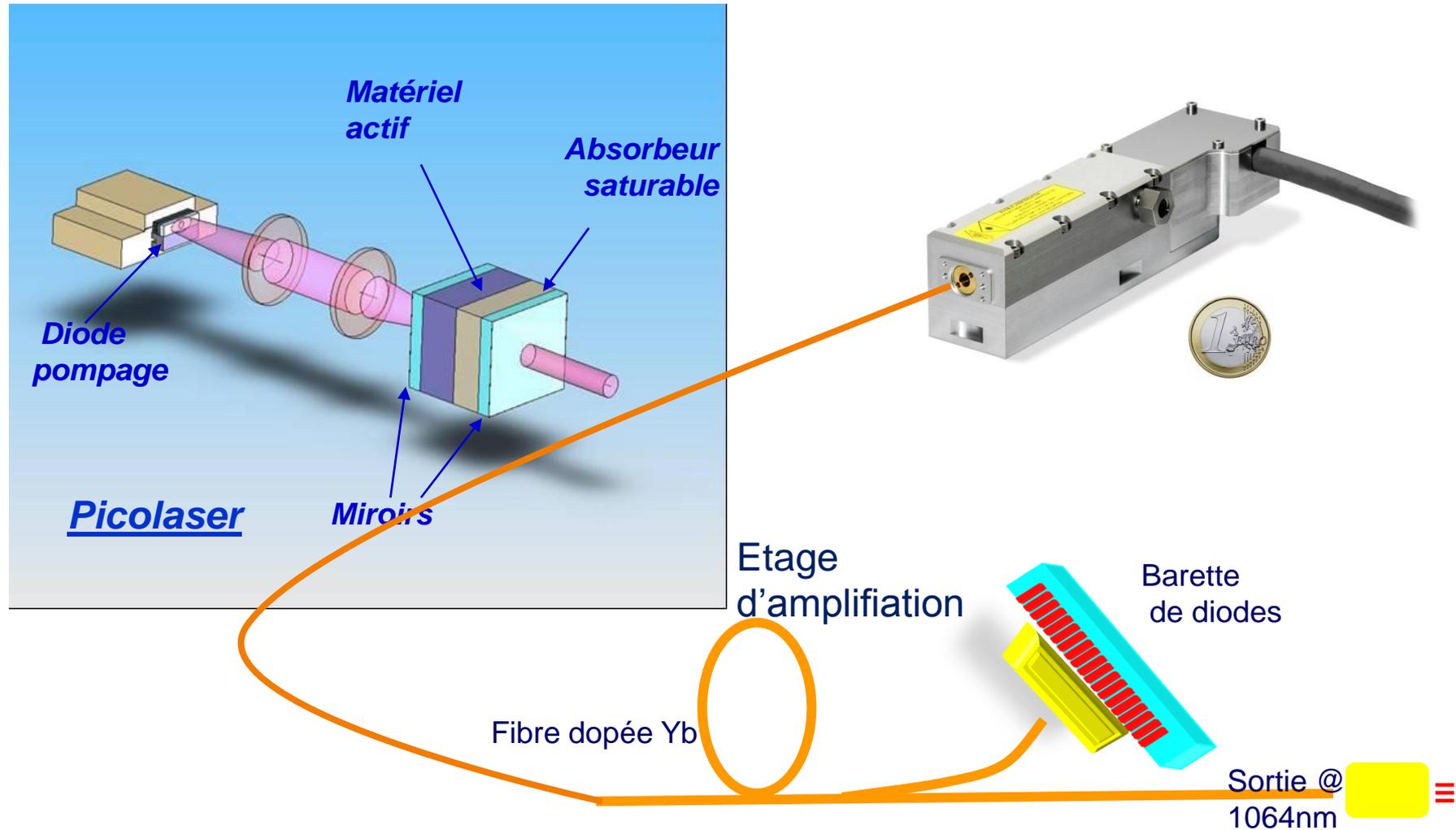


- Durée d'impulsion : centaine de ps
- Puissance crête : centaine de kW
- Irradiance crête : centaine de GW/cm²
- Longueur d'onde : 1064 nm et 532 nm

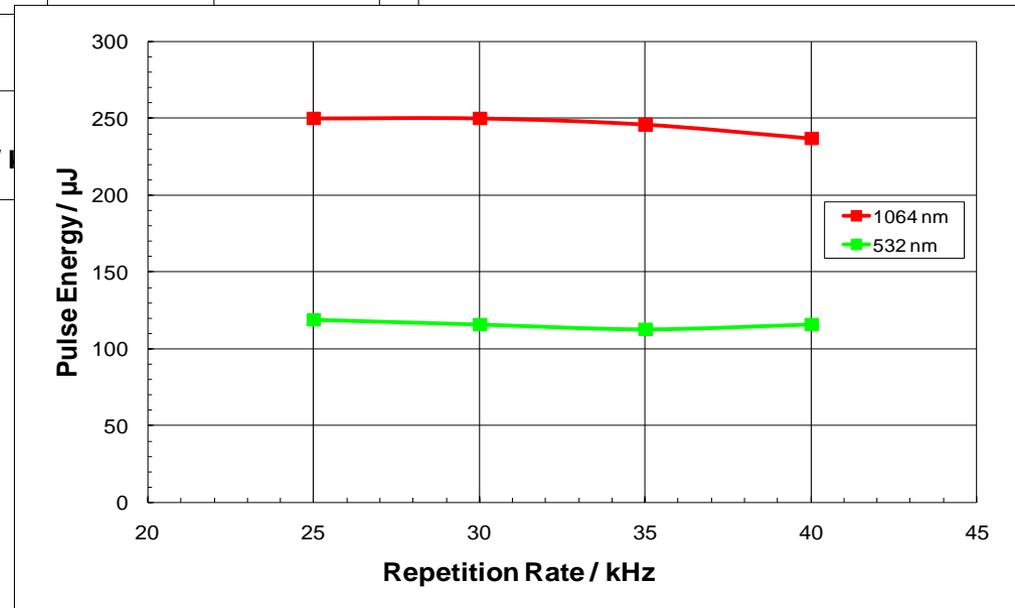
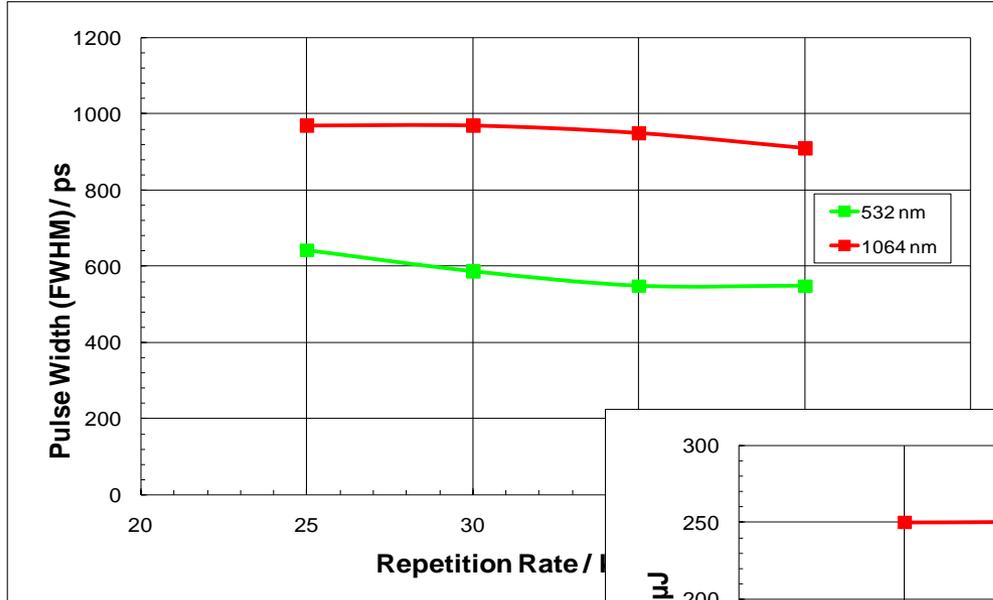
Positionnement du PicoSpark



Comment est-ce possible?



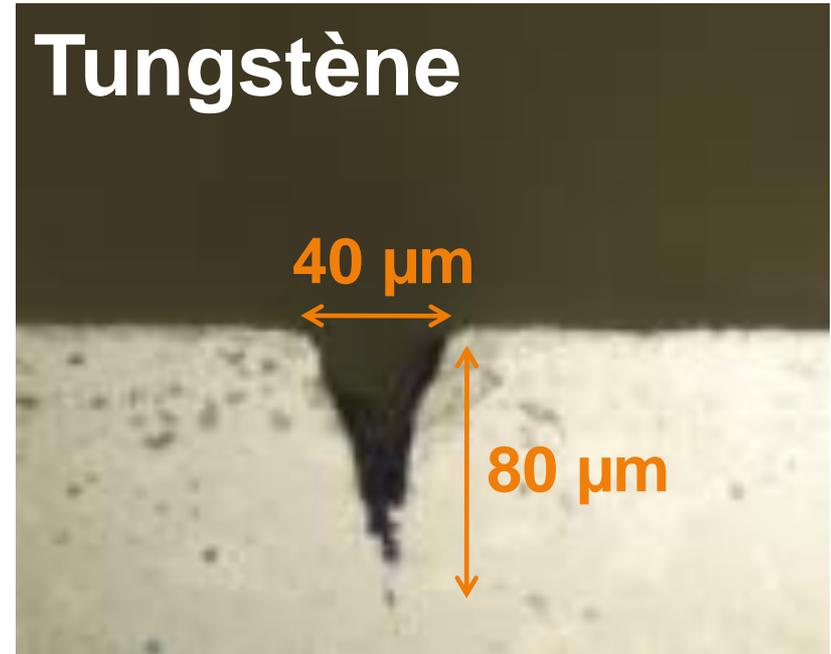
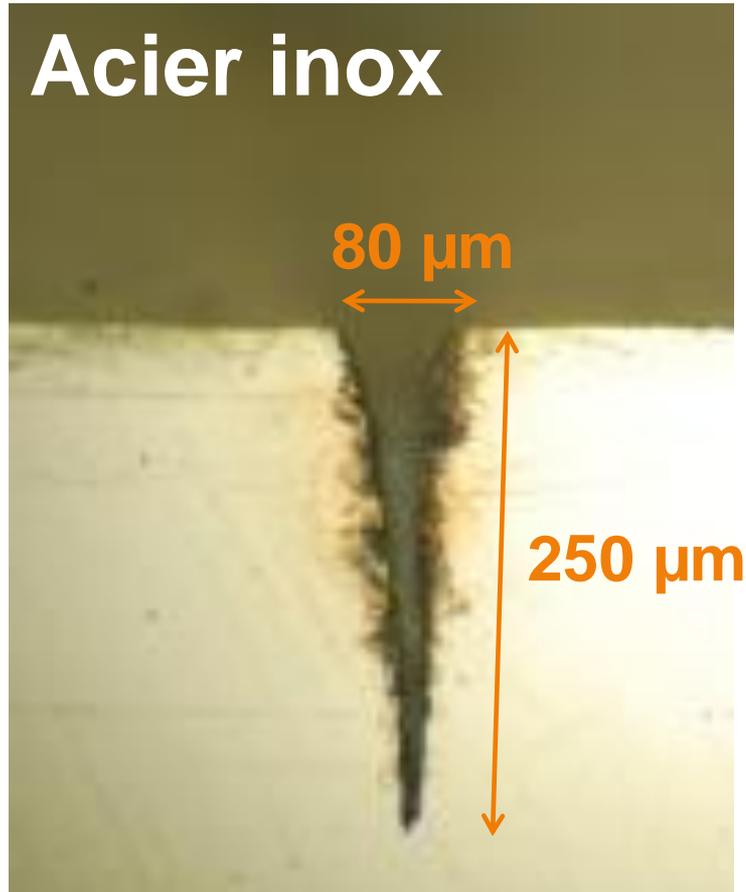
Energie et durée d'impulsion maintenues



Avantages

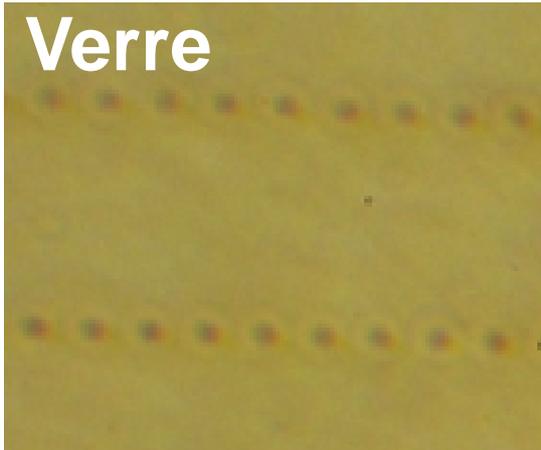
- Qualité du micro-usinage
- Conception simple
- Durée de vie et fiabilité
- Prix d'acquisition
- Coût d'utilisation
- Maintenance réduite
- Taille, poids

Micro-usinage de matériaux durs

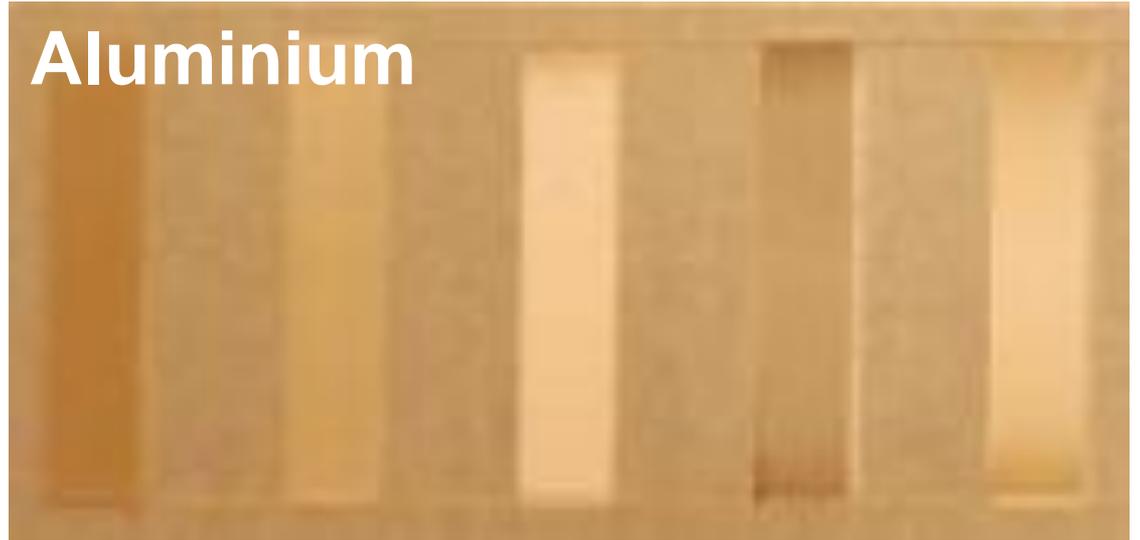


Marquage

Verre



Aluminium



Conclusion

- Possibilité d'effectuer du micro-usinage ultrarapide à des coûts raisonnables
 - Retour sur investissement rapide
 - Procédé fiable 24/7
- Génération économique d'impulsions courtes à haute puissance crête
 - 300 ps à 900 ps
 - Réglage flexible des cadences et puissances

Merci

Features & benefits

Ultrashort pulses that stay constant while varying rep rate or pulse energy

As low as 500ps duration at 532nm, 900ps at 1064nm

High peak power

125kW per pulse, with 550GW/cm² irradiance, at 532nm; 250kW per pulse, with 700GW/cm² irradiance, at 1064nm

Variable Repetition rate

Adjustable from 20kHz to 40kHz

Adjustable pulse energy

Pulse energy turned on in <300us, turned off in <600us

Excellent beam quality

Gaussian, TEM00, M²≤1.4

Efficient, air cooled

Typically consumes <350W

Licensed Technology

Exclusive license on Passively Q-switched pico-second microchip lasers: US Patent 5394413

License on fiber lasers and amplifiers: US Patent 5818630

CDRH compliant

Optional features

Increased pulse energy by relaxing M² or, at 1064nm, by removing isolator

1064nm & 532nm Passively Q-Switched Nd:YAG lasers: high irradiance, multiwatt

PicoSpark™ brings together Passively Q-Switched (PQS) microchip laser technology with fiber amplification, resulting in a multiwatt laser that generates pulses with hundreds of kilowatt peak power and hundreds of gigawatt per square centimeter irradiance.

A PQS microchip laser is the seed of PicoSpark™ and sets the pulse width, while allowing the user to vary the pulse energy (or peak power) and the repetition rate independently of each other. The output is free-space coupled, preserving peak power and beam quality.

The PicoSpark™ HNP series emits 5.5W at 1064nm; the HNG series emits 3.5W at 532nm, generated by harmonic conversion, both with an M² of 1.4 or lower.



Fiches techniques disponibles à la sortie

PicoSpark™ HNX lasers

Model	HNP-06P-100	HNG-03P-100
Wavelength (nm)	1064	532
M ²	1.3	1.3
Energy/Pulse (µJ)	200	100
Pulse Width (ps)	900	600
Peak Power (kW)	220	170
Repetition rate (kHz)	20-40	20-40
Average Power (W)	5.5	3

Typical values

Applications

- ▶ Micromachining
 - Scribing silicon and sapphire
 - Edge isolation
 - Drilling in steel
 - Ablation of copper
 - Cutting of tungsten
- ▶ Marking
 - Glass inscribing
 - Diamond graphitization
- ▶ Instrumentation
 - Laser Induced Breakdown Spectroscopy
 - Raman spectroscopy
 - Supercontinuum generation
 - Ranging
 - Differential absorption LIDAR
- ▶ Biophotonics
 - Microsurgery
 - Dense tissue ablation
 - Tattoo removal

Stand D3, halle 9

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GMP SA Siège principal : Avenue des Baumettes 17 CH-1020 Renens Tel. 021 633 21 21 Fax. 021 633 21 29 Info@gmp.ch
 GMP SA Succursale de Zürich : Dübendorferstrasse 11a CH-6117 Fällanden Tel. 044 825 34 00 Fax. 044 825 34 01 Info@gmp.ch

Marcel Dubey
 marcel.dubey@gmp.ch